

# OPA5614

# Yellow Green LED Chip

GaP/GaP

**1. Material** Substrate GaP (N Type)  
Epitaxial Layer GaP (P/N Type)

**2. Electrode** N(Cathode) Side Gold Alloy  
P(Anode) Side Gold Alloy

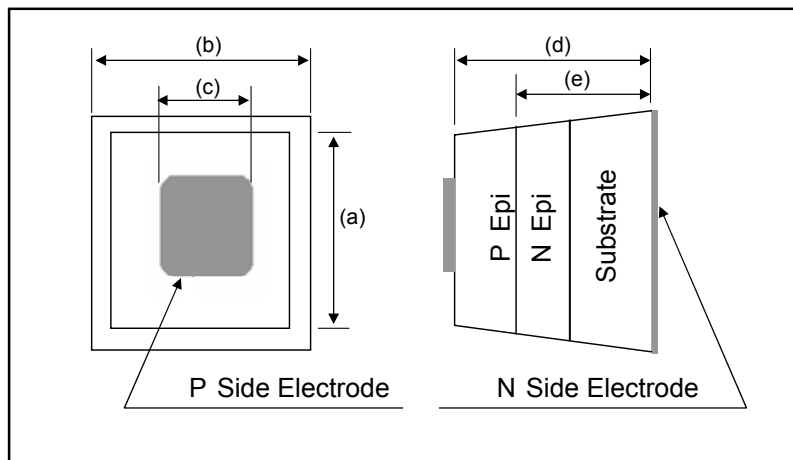
### 3. Electro-Optical Characteristics

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Forward Voltage	$V_{F(1)}$		1.8		V	IF=1mA
	$V_{F(2)}$		2.2	2.3	V	IF=20mA
Reverse Voltage	$V_R$	8			V	IR=10uA
Brightness	Iv	300	450		mcd	IF=20mA
Wavelength	$\lambda_d$		572		nm	IF=20mA
	$\Delta\lambda$		30		nm	IF=20mA

※ Note : Brightness is measured by Sorter E/T system with bare chip.

**4. Mechanical Data**

(a) Emission Area	-----	11mil x 11mil
(b) Bottom Area	-----	12mil x 12mil
(c) Bonding Pad	-----	120um
(d) Chip Thickness	-----	11mil
(e) Junction Height	-----	8.4mil



## AUK Corp.

Eoyang factory, 513-5 Eoyang-dong, Iksan, 570-210, Ko

Tel. +82 63 839 1111 Fax. +82 63 835 8259

[www.auk.co.kr](http://www.auk.co.kr)

